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What is claimed is:

1. A ceramic electronic device comprising:

a ceramic element;

an external electrode on said ceramic element; and

a protective layer on said ceramic element and external electrode, said protective layer being formed through impregnating a compound into said ceramic element and external electrode and through dehydrationcondensation, said compound being expressed by a formula of:

where R is an epoxy group, alkyl group, aryl group, perfluoroaryl group, or mixture thereof, n is a natural number, and R' is an alkyl group having 1 to 4 carbon atoms, hydrogen, or halogen atom, wherein at least one of R' is hydrogen.

- A ceramic electronic device according to claim 1, wherein the ceramic element is a sintered dielectric material.
 - 3. A ceramic electronic device comprising:

a ceramic element:

an external electrode on said ceramic element; and

a protective layer on said ceramic element and external electrode, said protective layer being formed through impregnating, into said ceramic element and external electrode and through dehydration-condensation, said compound being expressed by a formula of:

where R is an epoxy group, alkyl group, aryl group, perfluoroaryl group, or mixture thereof, n is a natural number, and R' is an alkyl group having 1 to 4

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carbon atoms, hydrogen, or halogen atom, wherein at least one of R' is hydrogen.

- 4. A ceramic electronic device according to claim 3, wherein the 5 ceramic element is a sintered dielectric material.
 - 5. A method of manufacturing a ceramic electronic device, comprising the steps of:

providing a ceramic electronic device including a ceramic element and an external electrode on the ceramic element;

plating the external electrode;

immersing the ceramic electronic device into a solution containing a compound expressed by a formula of:

$$R-C_nH_{2n}-Si-(OR')_3$$

where R is an epoxy group, alkyl group, aryl group, perfluoroaryl group, or mixture thereof, n is a natural number, and R' is an alkyl group having 1 to 4 carbon atoms, hydrogen, or halogen atom, wherein at least one of R' is hydrogen; and

taking out the immersed ceramic electronic device from the solution and subjecting the ceramic electronic device to heat treatment.

6. A method according to claim 5, wherein said step of providing the ceramic electronic device includes the sub-steps of:

forming the ceramic element through stacking an internal electrode and a ceramic layer; and

forming the external electrodes on the ceramic element, being electrically connected to the internal electrode.

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7. A method of manufacturing a ceramic electronic device comprising the steps of:

providing a ceramic electronic device including a ceramic element and

5 an external electrode on the ceramic element;

plating the external electrode;

immersing the ceramic electronic device into a solution containing a compound expressed by a formula of:

where R is an epoxy group, alkyl group, aryl group, perfluoroaryl group, or mixture thereof, n is a natural number, and R' is an alkyl group having 1 to 4 carbon atoms, hydrogen, or halogen atom, wherein at least one of R' is hydrogen; and

taking out the immersed ceramic electronic device from the solution and subjecting the ceramic electronic device to heat treatment.

8. A method according to claim 7, wherein said step of providing the ceramic electronic device includes the sub-steps of:

forming the ceramic element through stacking an internal electrode and a ceramic layer; and

forming the external electrode on the ceramic element, being electrically connected to the internal electrode.